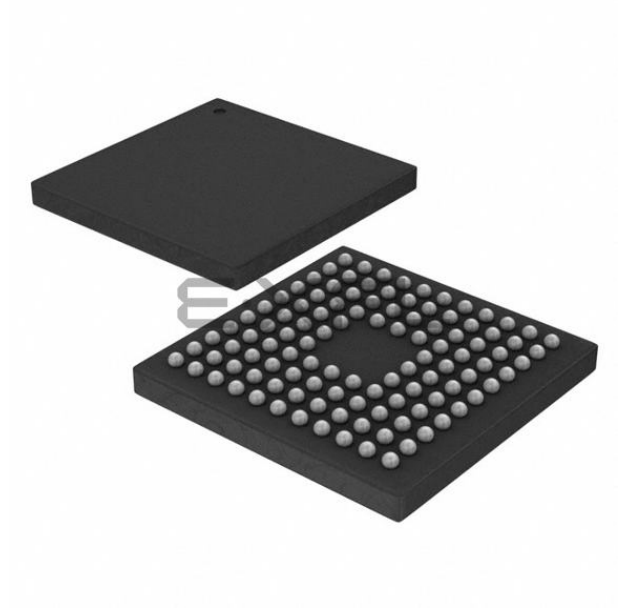

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I²C, IrDA, LINbus, MMC/SD/SDIO, QSPI, SmartCard, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	87
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	512K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 16x12b SAR; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	112-LFBGA
Supplier Device Package	112-BGA (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32gg11b420f2048gl112-br

Ordering Code	Flash (kB)	RAM (kB)	DC-DC Converter	USB	Ethernet	QSPI	SDIO	LCD	GPIO	Package	Temp Range
EFM32GG11B520F2048GQ64-A	2048	512	Yes	No	No	No	No	Yes	50	QFP64	-40 to +85°C
EFM32GG11B510F2048GQ64-A	2048	384	Yes	No	No	No	No	Yes	50	QFP64	-40 to +85°C
EFM32GG11B520F2048GM64-A	2048	512	Yes	No	No	No	No	Yes	53	QFN64	-40 to +85°C
EFM32GG11B510F2048GM64-A	2048	384	Yes	No	No	No	No	Yes	53	QFN64	-40 to +85°C
EFM32GG11B520F2048IQ64-A	2048	512	Yes	No	No	No	No	Yes	50	QFP64	-40 to +125°C
EFM32GG11B510F2048IQ64-A	2048	384	Yes	No	No	No	No	Yes	50	QFP64	-40 to +125°C
EFM32GG11B520F2048IM64-A	2048	512	Yes	No	No	No	No	Yes	53	QFN64	-40 to +125°C
EFM32GG11B510F2048IM64-A	2048	384	Yes	No	No	No	No	Yes	53	QFN64	-40 to +125°C
EFM32GG11B420F2048GL120-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	93	BGA120	-40 to +85°C
EFM32GG11B420F2048IL120-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	93	BGA120	-40 to +125°C
EFM32GG11B420F2048GL112-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	87	BGA112	-40 to +85°C
EFM32GG11B420F2048IL112-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	87	BGA112	-40 to +125°C
EFM32GG11B420F2048GQ100-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	83	QFP100	-40 to +85°C
EFM32GG11B420F2048IQ100-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	83	QFP100	-40 to +125°C
EFM32GG11B420F2048GQ64-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	50	QFP64	-40 to +85°C
EFM32GG11B420F2048GM64-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	53	QFN64	-40 to +85°C
EFM32GG11B420F2048IQ64-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	50	QFP64	-40 to +125°C
EFM32GG11B420F2048IM64-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	53	QFN64	-40 to +125°C
EFM32GG11B320F2048GL112-A	2048	512	No	No	No	No	No	Yes	90	BGA112	-40 to +85°C
EFM32GG11B310F2048GL112-A	2048	384	No	No	No	No	No	Yes	90	BGA112	-40 to +85°C
EFM32GG11B320F2048GQ100-A	2048	512	No	No	No	No	No	Yes	86	QFP100	-40 to +85°C
EFM32GG11B310F2048GQ100-A	2048	384	No	No	No	No	No	Yes	86	QFP100	-40 to +85°C
EFM32GG11B120F2048GQ64-A	2048	512	No	No	No	No	No	No	53	QFP64	-40 to +85°C
EFM32GG11B110F2048GQ64-A	2048	384	No	No	No	No	No	No	53	QFP64	-40 to +85°C
EFM32GG11B120F2048GM64-A	2048	512	No	No	No	No	No	No	56	QFN64	-40 to +85°C
EFM32GG11B110F2048GM64-A	2048	384	No	No	No	No	No	No	56	QFN64	-40 to +85°C
EFM32GG11B120F2048IQ64-A	2048	512	No	No	No	No	No	No	53	QFP64	-40 to +125°C
EFM32GG11B110F2048IQ64-A	2048	384	No	No	No	No	No	No	53	QFP64	-40 to +125°C
EFM32GG11B120F2048IM64-A	2048	512	No	No	No	No	No	No	56	QFN64	-40 to +125°C
EFM32GG11B110F2048IM64-A	2048	384	No	No	No	No	No	No	56	QFN64	-40 to +125°C

3.2.4 EM2 and EM3 Power Domains

The EFM32GG11 has three independent peripheral power domains for use in EM2 and EM3. Two of these domains are dynamic and can be shut down to save energy. Peripherals associated with the two dynamic power domains are listed in Table 3.1 EM2 and EM3 Peripheral Power Subdomains on page 13. If all of the peripherals in a peripheral power domain are unused, the power domain for that group will be powered off in EM2 and EM3, reducing the overall current consumption of the device. Other EM2, EM3, and EM4-capable peripherals and functions not listed in the table below reside on the primary power domain, which is always on in EM2 and EM3.

Table 3.1. EM2 and EM3 Peripheral Power Subdomains

Peripheral Power Domain 1	Peripheral Power Domain 2
ACMP0	ACMP1
PCNT0	PCNT1
ADC0	PCNT2
LETIMER0	CSEN
LESENSE	VDAC0
APORT	LEUART0
-	LEUART1
-	LETIMER1
-	I2C0
-	I2C1
-	I2C2
-	IDAC
-	ADC1
-	ACMP2
-	ACMP3
-	LCD
-	RTC

3.3 General Purpose Input/Output (GPIO)

EFM32GG11 has up to 144 General Purpose Input/Output pins. GPIO are organized on three independent supply rails, allowing for interface to multiple logic levels in the system simultaneously. Each GPIO pin can be individually configured as either an output or input. More advanced configurations including open-drain, open-source, and glitch-filtering can be configured for each individual GPIO pin. The GPIO pins can be overridden by peripheral connections, like SPI communication. Each peripheral connection can be routed to several GPIO pins on the device. The input value of a GPIO pin can be routed through the Peripheral Reflex System to other peripherals. The GPIO subsystem supports asynchronous external pin interrupts.

3.4 Clocking

3.4.1 Clock Management Unit (CMU)

The Clock Management Unit controls oscillators and clocks in the EFM32GG11. Individual enabling and disabling of clocks to all peripheral modules is performed by the CMU. The CMU also controls enabling and configuration of the oscillators. A high degree of flexibility allows software to optimize energy consumption in any specific application by minimizing power dissipation in unused peripherals and oscillators.

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit

Note:

1. The minimum voltage required in bypass mode is calculated using R_{BYP} from the DCDC specification table. Requirements for other loads can be calculated as $V_{DVDD\_min}+I_{LOAD} * R_{BYP\_max}$.
2. VREGVDD must be tied to AVDD. Both VREGVDD and AVDD minimum voltages must be satisfied for the part to operate.
3. The system designer should consult the characteristic specs of the capacitor used on DECOUPLE to ensure its capacitance value stays within the specified bounds across temperature and DC bias.
4. VSCALE0 to VSCALE2 voltage change transitions occur at a rate of 10 mV / usec for approximately 20 usec. During this transition, peak currents will be dependent on the value of the DECOUPLE output capacitor, from 35 mA (with a 1 µF capacitor) to 70 mA (with a 2.7 µF capacitor).
5. When the CSEN peripheral is used with chopping enabled (CSEN_CTRL_CHOPEN = ENABLE), IOVDD must be equal to AVDD.
6. The maximum limit on T_A may be lower due to device self-heating, which depends on the power dissipation of the specific application. T_A (max) = T_J (max) - ($THETA_{JA}$ x PowerDissipation). Refer to the Absolute Maximum Ratings table and the Thermal Characteristics table for T_J and $THETA_{JA}$.

4.1.3 Thermal Characteristics

Table 4.3. Thermal Characteristics

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Thermal resistance, QFN64 Package	$THETA_{JA\_QFN64}$	4-Layer PCB, Air velocity = 0 m/s	—	17.8	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	15.4	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	13.8	—	°C/W
Thermal resistance, TQFP64 Package	$THETA_{JA\_TQFP64}$	4-Layer PCB, Air velocity = 0 m/s	—	33.9	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	32.1	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	30.1	—	°C/W
Thermal resistance, TQFP100 Package	$THETA_{JA\_TQFP100}$	4-Layer PCB, Air velocity = 0 m/s	—	44.1	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	37.7	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	35.5	—	°C/W
Thermal resistance, BGA112 Package	$THETA_{JA\_BGA112}$	4-Layer PCB, Air velocity = 0 m/s	—	42.0	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	37.0	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	35.3	—	°C/W
Thermal resistance, BGA120 Package	$THETA_{JA\_BGA120}$	4-Layer PCB, Air velocity = 0 m/s	—	47.9	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	41.8	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	39.6	—	°C/W
Thermal resistance, BGA152 Package	$THETA_{JA\_BGA152}$	4-Layer PCB, Air velocity = 0 m/s	—	35.7	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	31.0	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	29.5	—	°C/W
Thermal resistance, BGA192 Package	$THETA_{JA\_BGA192}$	4-Layer PCB, Air velocity = 0 m/s	—	47.9	—	°C/W
		4-Layer PCB, Air velocity = 1 m/s	—	41.8	—	°C/W
		4-Layer PCB, Air velocity = 2 m/s	—	39.6	—	°C/W

4.1.7 Current Consumption

4.1.7.1 Current Consumption 3.3 V without DC-DC Converter

Unless otherwise indicated, typical conditions are: VREGVDD = AVDD = DVDD = 3.3 V. T = 25 °C. DCDC is off. Minimum and maximum values in this table represent the worst conditions across supply voltage and process variation at T = 25 °C.

Table 4.7. Current Consumption 3.3 V without DC-DC Converter

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Current consumption in EM0 mode with all peripherals disabled	I_{ACTIVE}	72 MHz HFRCO, CPU running Prime from flash	—	120	—	µA/MHz
		72 MHz HFRCO, CPU running while loop from flash	—	120	TBD	µA/MHz
		72 MHz HFRCO, CPU running CoreMark loop from flash	—	140	—	µA/MHz
		50 MHz crystal, CPU running while loop from flash	—	123	—	µA/MHz
		48 MHz HFRCO, CPU running while loop from flash	—	122	TBD	µA/MHz
		32 MHz HFRCO, CPU running while loop from flash	—	124	—	µA/MHz
		26 MHz HFRCO, CPU running while loop from flash	—	126	TBD	µA/MHz
		16 MHz HFRCO, CPU running while loop from flash	—	131	—	µA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	319	TBD	µA/MHz
Current consumption in EM0 mode with all peripherals disabled and voltage scaling enabled	I_{ACTIVE_VS}	19 MHz HFRCO, CPU running while loop from flash	—	107	—	µA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	262	—	µA/MHz
Current consumption in EM1 mode with all peripherals disabled	I_{EM1}	72 MHz HFRCO	—	57	TBD	µA/MHz
		50 MHz crystal	—	60	—	µA/MHz
		48 MHz HFRCO	—	59	TBD	µA/MHz
		32 MHz HFRCO	—	61	—	µA/MHz
		26 MHz HFRCO	—	63	TBD	µA/MHz
		16 MHz HFRCO	—	68	—	µA/MHz
		1 MHz HFRCO	—	255	TBD	µA/MHz
Current consumption in EM1 mode with all peripherals disabled and voltage scaling enabled	I_{EM1_VS}	19 MHz HFRCO	—	55	—	µA/MHz
		1 MHz HFRCO	—	210	—	µA/MHz

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frequency limits	f_{HFRCO_BAND}	FREQRANGE = 0, FINETUNINGEN = 0	1	—	10	MHz
		FREQRANGE = 3, FINETUNINGEN = 0	2	—	17	MHz
		FREQRANGE = 6, FINETUNINGEN = 0	4	—	30	MHz
		FREQRANGE = 7, FINETUNINGEN = 0	5	—	34	MHz
		FREQRANGE = 8, FINETUNINGEN = 0	7	—	42	MHz
		FREQRANGE = 10, FINETUNINGEN = 0	12	—	58	MHz
		FREQRANGE = 11, FINETUNINGEN = 0	15	—	68	MHz
		FREQRANGE = 12, FINETUNINGEN = 0	18	—	83	MHz
		FREQRANGE = 13, FINETUNINGEN = 0	24	—	100	MHz
		FREQRANGE = 14, FINETUNINGEN = 0	28	—	119	MHz
		FREQRANGE = 15, FINETUNINGEN = 0	33	—	138	MHz
		FREQRANGE = 16, FINETUNINGEN = 0	43	—	163	MHz

Note:

1. Maximum DPLL lock time ~= 6 x (M+1) x t_{REF}, where t_{REF} is the reference clock period.

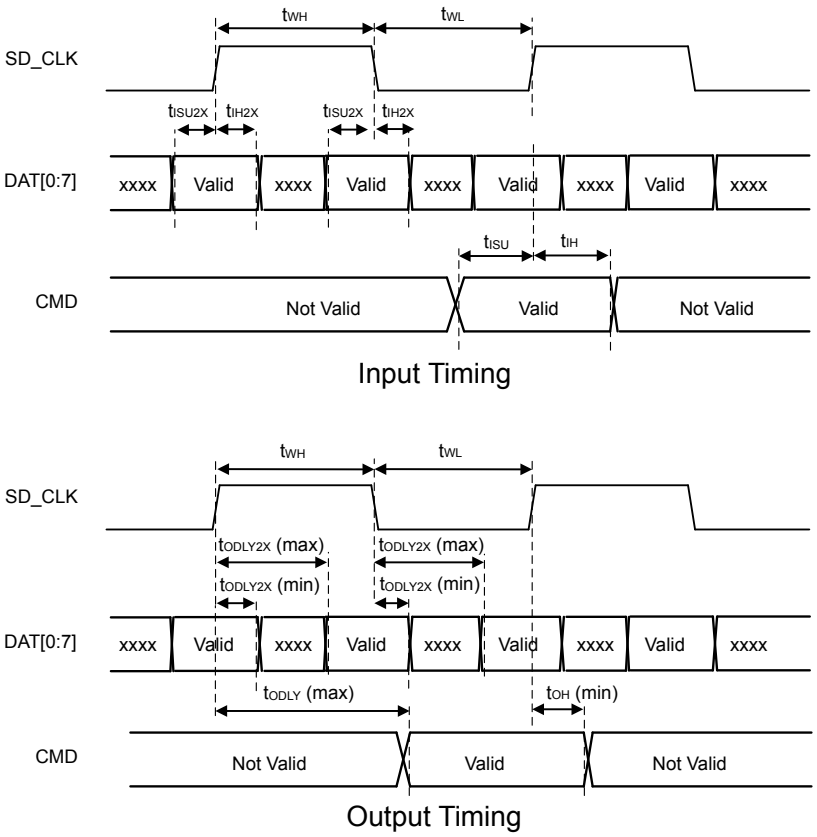

Figure 4.19. SDIO MMC DDR Mode Timing

SDIO MMC DDR Mode Timing at 3.0 V

Timing is specified for route location 0 at 3.0 V IOVDD with voltage scaling disabled. Slew rate for SD_CLK set to 7, all other GPIO set to 6, DRIVESTRENGTH = STRONG for all pins. SDIO_CTRL_TXDLYMUXSEL = 1. Loading between 5 and 10 pF on all pins or between 10 and 25 pF on all pins.

Table 4.53. SDIO MMC DDR Mode Timing (Location 0, 3V I/O)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Clock frequency during data transfer	F_{SD_CLK}	Using HFRCO, AUXHFRCO, or USHFRCO	—	—	20	MHz
		Using HFXO	—	—	TBD	MHz
Clock low time	t_{WL}	Using HFRCO, AUXHFRCO, or USHFRCO	22.6	—	—	ns
		Using HFXO	TBD	—	—	ns
Clock high time	t_{WH}	Using HFRCO, AUXHFRCO, or USHFRCO	22.6	—	—	ns
		Using HFXO	TBD	—	—	ns
Clock rise time	t_R		1.13	2.37	—	ns
Clock fall time	t_F		1.01	2.02	—	ns
Input setup time, CMD valid to SD_CLK	t_{ISU}		5.3	—	—	ns
Input hold time, SD_CLK to CMD change	t_{IH}		2.5	—	—	ns
Output delay time, SD_CLK to CMD valid	t_{ODLY}		0	—	16	ns
Output hold time, SD_CLK to CMD change	t_{OH}		3	—	—	ns
Input setup time, DAT[0:7] valid to SD_CLK	t_{ISU2X}		5.3	—	—	ns
Input hold time, SD_CLK to DAT[0:7] change	t_{IH2X}		2.5	—	—	ns
Output delay time, SD_CLK to DAT[0:7] valid	t_{ODLY2X}		0	—	16	ns
Output hold time, SD_CLK to DAT[0:7] change	t_{OH2X}		3	—	—	ns

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB2	M2	GPIO	PB3	M3	GPIO
PC6	M14	GPIO	VREGVSS	M15 N16	Voltage regulator VSS
VREGSW	M16	DCDC regulator switching node	PB4	N1	GPIO
PB5	N2	GPIO	PB6	N3	GPIO
PD5	N14	GPIO	PD4	N15	GPIO
PC0	P1	GPIO (5V)	PC1	P2	GPIO (5V)
PC2	P3	GPIO (5V)	PA8	P4	GPIO
PA11	P5	GPIO	PA13	P6	GPIO (5V)
PB9	P7	GPIO (5V)	PB12	P8	GPIO
PH2	P9	GPIO (5V)	PH5	P10	GPIO
PH8	P11	GPIO (5V)	PH11	P12	GPIO (5V)
PH13	P13	GPIO (5V)	PD0	P14	GPIO (5V)
PD3	P15	GPIO	PD8	P16	GPIO
PB7	R1	GPIO	PC3	R2	GPIO (5V)
PC5	R3	GPIO	PA9	R4	GPIO
BODEN	R5	Brown-Out Detector Enable. This pin may be left disconnected or tied to AVDD.	RESETn	R6	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB10	R7	GPIO (5V)	PH0	R8	GPIO (5V)
PH3	R9	GPIO (5V)	PH6	R10	GPIO
PH9	R11	GPIO (5V)	PH12	R12	GPIO (5V)
PH14	R13	GPIO (5V)	PH15	R14	GPIO (5V)
PD2	R15	GPIO (5V)	PD7	R16	GPIO
PB8	T1	GPIO	PC4	T2	GPIO
PA7	T3	GPIO	PA10	T4	GPIO
PA12	T5	GPIO (5V)	PA14	T6	GPIO
PB11	T7	GPIO	PH1	T8	GPIO (5V)
PH4	T9	GPIO	PH7	T10	GPIO (5V)
PH10	T11	GPIO (5V)	PB13	T12	GPIO
PB14	T13	GPIO	AVDD	T14	Analog power supply.
PD1	T15	GPIO	PD6	T16	GPIO

Note:

1. GPIO with 5V tolerance are indicated by (5V).
2. The pins PD13, PD14, and PD15 will not be 5V tolerant on all future devices. In order to preserve upgrade options with full hardware compatibility, do not use these pins with 5V domains.

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PG6	H1	GPIO (5V)	PG7	H2	GPIO (5V)
PG5	H3	GPIO (5V)	PE6	H12	GPIO
PE5	H13	GPIO	DVDD	H14	Digital power supply.
PG9	J1	GPIO (5V)	PG10	J2	GPIO (5V)
PG8	J3	GPIO (5V)	PE3	J12	GPIO
PE4	J13	GPIO	VREGVDD	J14	Voltage regulator VDD input
PG12	K1	GPIO	PG13	K2	GPIO
PG11	K3	GPIO (5V)	PE2	K12	GPIO
PE1	K13	GPIO (5V)	VREGSW	K14	DCDC regulator switching node
PG15	L1	GPIO (5V)	PB15	L2	GPIO (5V)
PG14	L3	GPIO	PC7	L12	GPIO
PE0	L13	GPIO (5V)	VREGVSS	L14	Voltage regulator VSS
PB0	M1	GPIO	PB1	M2	GPIO
PB4	M3	GPIO	PC0	M4	GPIO (5V)
PC3	M5	GPIO (5V)	PA9	M6	GPIO
BODEN	M7	Brown-Out Detector Enable. This pin may be left disconnected or tied to AVDD.	PA12	M8	GPIO (5V)
RESETn	M9	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.	PB10	M10	GPIO (5V)
PD1	M11	GPIO	PC6	M12	GPIO
PD5	M13	GPIO	PD8	M14	GPIO
PB7	N1	GPIO	PB2	N2	GPIO
PB5	N3	GPIO	PC2	N4	GPIO (5V)
PC5	N5	GPIO	PA8	N6	GPIO
PA11	N7	GPIO	PA14	N8	GPIO
PB11	N9	GPIO	PB12	N10	GPIO
PD0	N11	GPIO (5V)	PD2	N12	GPIO (5V)
PD4	N13	GPIO	PD7	N14	GPIO
PB8	P1	GPIO	PB3	P2	GPIO
PB6	P3	GPIO	PC1	P4	GPIO (5V)
PC4	P5	GPIO	PA7	P6	GPIO
PA10	P7	GPIO	PA13	P8	GPIO (5V)
PB9	P9	GPIO (5V)	PB13	P10	GPIO
PB14	P11	GPIO	AVDD	P12	Analog power supply.
PD3	P13	GPIO	PD6	P14	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PC1	J1	GPIO (5V)	PC3	J2	GPIO (5V)
PD15	J3	GPIO (5V)	PA12	J4	GPIO (5V)
PA9	J5	GPIO	PA10	J6	GPIO
PB9	J7	GPIO (5V)	PB10	J8	GPIO (5V)
PD2	J9	GPIO (5V)	PD3	J10	GPIO
PD4	J11	GPIO	PB7	K1	GPIO
PC4	K2	GPIO	PA13	K3	GPIO (5V)
PA11	K5	GPIO	RESETn	K6	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
AVDD	K8 K9 L10	Analog power supply.	PD1	K11	GPIO
PB8	L1	GPIO	PC5	L2	GPIO
PA14	L3	GPIO	PB11	L5	GPIO
PB12	L6	GPIO	PB13	L8	GPIO
PB14	L9	GPIO	PD0	L11	GPIO (5V)

Note:

1. GPIO with 5V tolerance are indicated by (5V).
2. The pins PD13, PD14, and PD15 will not be 5V tolerant on all future devices. In order to preserve upgrade options with full hardware compatibility, do not use these pins with 5V domains.

GPIO Name	Pin Alternate Functionality / Description				
	Analog	EBI	Timers	Communication	Other
PH11	BUSACMP3Y BUSACMP3X	EBI_A23 #2	TIM5_CC1 #1 WTIM1_CC3 #6	US5_RX #3 U1_TX #5 I2C1_SDA #5	
PH13	BUSACMP3Y BUSACMP3X	EBI_A25 #2	TIM5_CC0 #2 WTIM1_CC1 #7 PCNT2_S1IN #7	US5_CS #3 U1_CTS #5 I2C1_SDA #6	
PD0	VDAC0_OUT0ALT / OPA0_OUTALT #4 OPA2_OUTALT BUSADC0Y BUSADC0X	EBI_A04 #1 EBI_A13 #3	TIM4_CDTI0 TIM6_CC2 #5 WTIM1_CC2 #0 PCNT2_S0IN #0	CAN0_RX #2 US1_TX #1	
PD3	BUSADC0Y BUSADC0X OPA2_N	EBI_A07 #1 EBI_A16 #3	TIM4_CDTI2 TIM0_CC2 #2 TIM6_CC2 #6 WTIM1_CC1 #1 WTIM2_CC0 #5	CAN1_RX #2 US1_CS #1 LEU1_RX #2	ETM_TD1 #0 ETM_TD1 #2
PD8	BU_VIN	EBI_A12 #1	WTIM1_CC2 #2	US2_RTS #5	CMU_CLK1 #1 PRS_CH12 #2 ACMP2_O #0
PB7	LFXTAL_P		TIM0_CDTI0 #4 TIM1_CC0 #3	US0_TX #4 US1_CLK #0 US3_RX #2 US4_TX #0 U0_CTS #4	PRS_CH22 #0
PC3	VDAC0_OUT0ALT / OPA0_OUTALT #3 BUSACMP0Y BUSACMP0X	EBI_AD10 #1 EBI_CS3 #2 EBI_BL1 #3 EBI_NANDREn #0	TIM0_CDTI1 #3 TIM2_CC1 #5 WTIM0_CC2 #7 LETIM1_OUT1 #3	ETH_TSUTMRTOG #2 CAN1_TX #0 US1_CLK #4 US2_RX #0	LES_CH3 PRS_CH11 #1
PC5	BUSACMP0Y BUSACMP0X OPA0_N	EBI_AD12 #1 EBI_WEn #2 EBI_NANDWEn #0 EBI_A00 #3	TIM0_CC1 #5 LETIM0_OUT1 #3 PCNT1_S1IN #3	SDIO_WP #1 US2_CS #0 US4_CS #0 U0_RX #4 U1_RTS #4 I2C1_SCL #0	LES_CH5 PRS_CH19 #2
PA9	BUSAY BUSBX LCD_SEG37	EBI_AD15 #1 EBI_A03 #3 EBI_DTEN #0	TIM2_CC1 #0 TIM0_CC1 #6 WTIM2_CC0 #0 LETIM0_OUT1 #6	US2_CLK #2	PRS_CH9 #0
PB10	BUSBY BUSAX	EBI_BL0 #2 EBI_A01 #1 EBI_A04 #0 EBI_A10 #3	WTIM2_CC1 #2 LETIM0_OUT1 #7	SDIO_CD #3 CAN0_TX #3 US1_RTS #0 US2_CTS #3 U1_RX #2	PRS_CH9 #2 ACMP1_O #6
PH0	BUSADC1Y BUSADC1X	EBI_DCLK #2	WTIM2_CC2 #4	US0_CTS #6 LEU1_TX #5	
PH3	BUSADC1Y BUSADC1X	EBI_HSNC #2	TIM6_CC1 #3	US1_RTS #6	
PH6	BUSADC1Y BUSADC1X	EBI_A18 #2	TIM6_CDTI1 #3 WTIM2_CC2 #6	US4_CLK #4	
PH9	BUSACMP3Y BUSACMP3X	EBI_A21 #2	TIM6_CC1 #4 WTIM1_CC1 #6 WTIM2_CC2 #7	US4_RTS #4	
PH12	BUSACMP3Y BUSACMP3X	EBI_A24 #2	TIM5_CC2 #1 WTIM1_CC0 #7	US5_CLK #3 U1_RX #5 I2C1_SCL #5	

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
EBI_CS1	0: PD10 1: PA11 2: PC1 3: PB1	4: PE9	External Bus Interface (EBI) Chip Select output 1.
EBI_CS2	0: PD11 1: PA12 2: PC2 3: PB2	4: PE10	External Bus Interface (EBI) Chip Select output 2.
EBI_CS3	0: PD12 1: PB15 2: PC3 3: PB3	4: PE11	External Bus Interface (EBI) Chip Select output 3.
EBI_CSTFT	0: PA7 1: PF6 2: PB12 3: PA0		External Bus Interface (EBI) Chip Select output TFT.
EBI_DCLK	0: PA8 1: PF7 2: PH0 3: PA1		External Bus Interface (EBI) TFT Dot Clock pin.
EBI_DTEN	0: PA9 1: PD9 2: PH1 3: PA2		External Bus Interface (EBI) TFT Data Enable pin.
EBI_HSNC	0: PA11 1: PD11 2: PH3 3: PA4		External Bus Interface (EBI) TFT Horizontal Synchronization pin.
EBI_NANDREn	0: PC3 1: PD15 2: PB9 3: PC4	4: PC15 5: PF12	External Bus Interface (EBI) NAND Read Enable output.
EBI_NANDWEn	0: PC5 1: PD14 2: PA13 3: PC2	4: PC14 5: PF11	External Bus Interface (EBI) NAND Write Enable output.
EBI_REn	0: PF5 1: PA14 2: PA12 3: PC0	4: PF9 5: PF5	External Bus Interface (EBI) Read Enable output.
EBI_VSNC	0: PA10 1: PD10 2: PH2 3: PA3		External Bus Interface (EBI) TFT Vertical Synchronization pin.
EBI_WEn	0: PF4 1: PA13 2: PC5 3: PB6	4: PF8 5: PF4	External Bus Interface (EBI) Write Enable output.
ETH_MDC	0: PB4 1: PD14 2: PC1 3: PA6		Ethernet Management Data Clock.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
LCD_BEXT	0: PA14		LCD external supply bypass in step down or charge pump mode. If using the LCD in step-down or charge pump mode, a 1 uF (minimum) capacitor between this pin and VSS is required. To reduce supply ripple, a larger capcitor of approximately 1000 times the total LCD segment capacitance may be used. If using the LCD with the internal supply source, this pin may be left unconnected or used as a GPIO.
LCD_COM0	0: PE4		LCD driver common line number 0.
LCD_COM1	0: PE5		LCD driver common line number 1.
LCD_COM2	0: PE6		LCD driver common line number 2.
LCD_COM3	0: PE7		LCD driver common line number 3.
LCD_SEG0	0: PF2		LCD segment line 0.
LCD_SEG1	0: PF3		LCD segment line 1.
LCD_SEG2	0: PF4		LCD segment line 2.
LCD_SEG3	0: PF5		LCD segment line 3.
LCD_SEG4	0: PE8		LCD segment line 4.
LCD_SEG5	0: PE9		LCD segment line 5.
LCD_SEG6	0: PE10		LCD segment line 6.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
LCD_SEG7	0: PE11		LCD segment line 7.
LCD_SEG8	0: PE12		LCD segment line 8.
LCD_SEG9	0: PE13		LCD segment line 9.
LCD_SEG10	0: PE14		LCD segment line 10.
LCD_SEG11	0: PE15		LCD segment line 11.
LCD_SEG12	0: PA15		LCD segment line 12.
LCD_SEG13	0: PA0		LCD segment line 13.
LCD_SEG14	0: PA1		LCD segment line 14.
LCD_SEG15	0: PA2		LCD segment line 15.
LCD_SEG16	0: PA3		LCD segment line 16.
LCD_SEG17	0: PA4		LCD segment line 17.
LCD_SEG18	0: PA5		LCD segment line 18.
LCD_SEG19	0: PA6		LCD segment line 19.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
LES_ALTEX6	0: PE12		LESENSE alternate excite output 6.
LES_ALTEX7	0: PE13		LESENSE alternate excite output 7.
LES_CH0	0: PC0		LESENSE channel 0.
LES_CH1	0: PC1		LESENSE channel 1.
LES_CH2	0: PC2		LESENSE channel 2.
LES_CH3	0: PC3		LESENSE channel 3.
LES_CH4	0: PC4		LESENSE channel 4.
LES_CH5	0: PC5		LESENSE channel 5.
LES_CH6	0: PC6		LESENSE channel 6.
LES_CH7	0: PC7		LESENSE channel 7.
LES_CH8	0: PC8		LESENSE channel 8.
LES_CH9	0: PC9		LESENSE channel 9.
LES_CH10	0: PC10		LESENSE channel 10.

Table 5.23. ACMP0 Bus and Pin Mapping

Port	Bus	CH31	CH30	CH29	CH28	CH27	CH26	CH25	CH24	CH23	CH22	CH21	CH20	CH19	CH18	CH17	CH16	CH15	CH14	CH13	CH12	CH11	CH10	CH9	CH8	CH7	CH6	CH5	CH4	CH3	CH2	CH1	CH0
APORT0X	BUSACMP0X																									PC7	PC6	PC5	PC4	PC3	PC2	PC1	PC0
APORT0Y	BUSACMP0Y																									PC7	PC6	PC5	PC4	PC3	PC2	PC1	PC0
APORT1X	BUSAX		PB14		PB12		PB10				PB6		PB4		PB2		PB0		PA14		PA12		PA10		PA8		PA6		PA4		PA2		PA0
APORT1Y	BUSAY	PB15		PB13		PB11		PB9				PB5		PB3		PB1		PA15		PA13		PA11		PA9		PA7		PA5		PA3		PA1	
APORT2X	BUSBX	PB15		PB13		PB11		PB9				PB5		PB3		PB1		PA15		PA13		PA11		PA9		PA7		PA5		PA3		PA1	
APORT2Y	BUSBY		PB14		PB12		PB10				PB6		PB4		PB2		PB0		PA14		PA12		PA10		PA8		PA6		PA4		PA2		PA0
APORT3X	BUSCX		PF14		PF12		PF10		PF8		PF6		PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				PE0
APORT3Y	BUSCY	PF15		PF13		PF11		PF9		PF7		PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5				PE1	
APORT4X	BUSDX	PF15		PF13		PF11		PF9		PF7		PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5				PE1	
APORT4Y	BUSDY		PF14		PF12		PF10		PF8		PF6		PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				PE0

7.2 BGA152 PCB Land Pattern

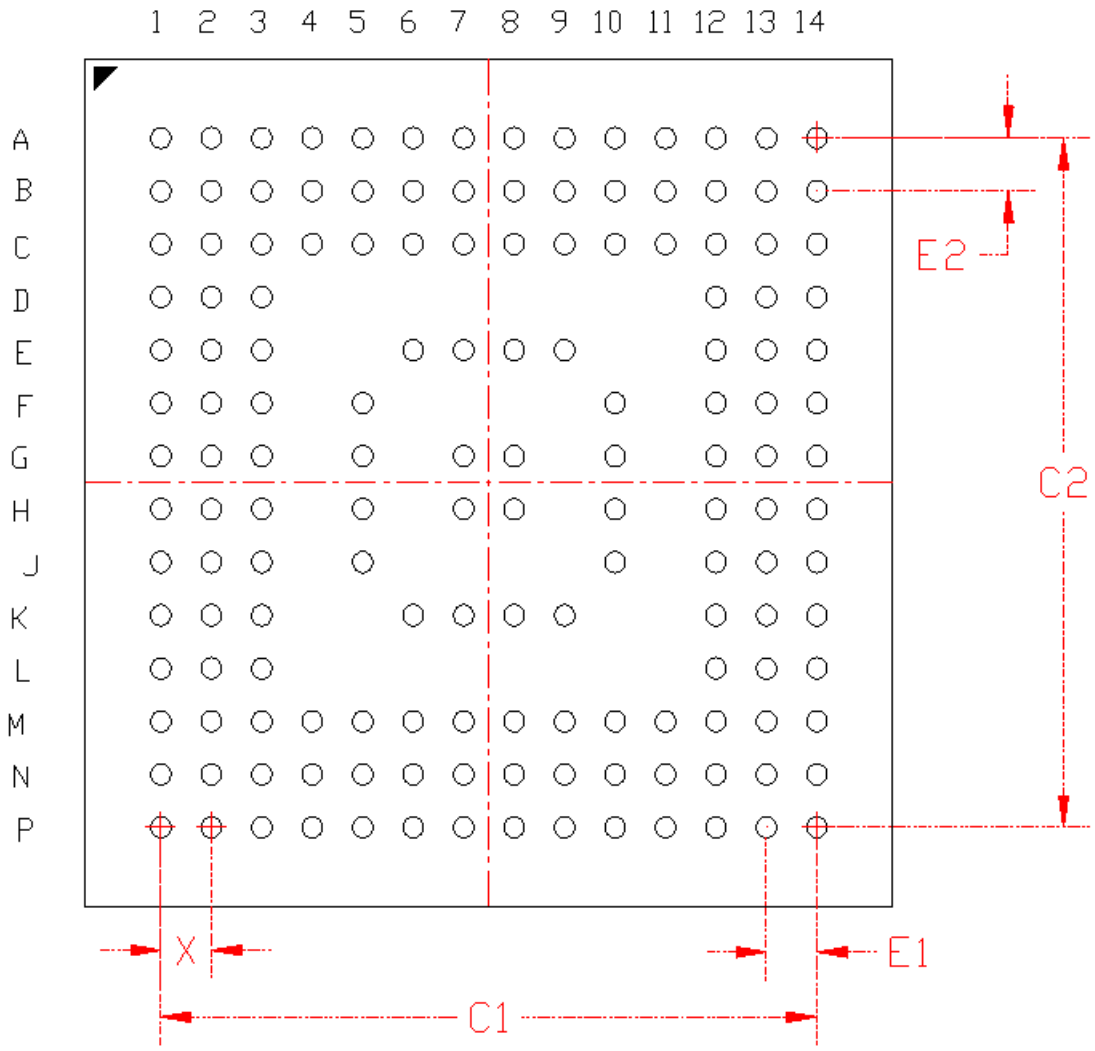

Figure 7.2. BGA152 PCB Land Pattern Drawing

Table 7.2. BGA152 PCB Land Pattern Dimensions

Dimension	Min	Nom	Max
X		0.20	
C1		6.50	
C2		6.50	
E1		0.5	
E2		0.5	

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
6. The stencil thickness should be 0.125 mm (5 mils).
7. The ratio of stencil aperture to land pad size should be 1:1.
8. A No-Clean, Type-3 solder paste is recommended.
9. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

Table 8.1. BGA120 Package Dimensions

Dimension	Min	Typ	Max
A	0.78	0.84	0.90
A1	0.13	0.18	0.23
A3	0.17	0.21	0.25
A2		0.45 REF	
D		7.00 BSC	
e		0.50 BSC	
E		7.00 BSC	
D1		6.00 BSC	
E1		6.00 BSC	
b	0.20	0.25	0.30
aaa		0.10	
bbb		0.10	
ddd		0.08	
eee		0.15	
fff		0.05	

Note:
1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

Table 10.2. TQFP100 PCB Land Pattern Dimensions

Dimension	Min	Nom	Max
C1		15.4	
C2		15.4	
E		0.50 BSC	
X		0.30	
Y		1.50	

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
5. The stencil thickness should be 0.125 mm (5 mils).
6. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
7. A No-Clean, Type-3 solder paste is recommended.
8. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

10.3 TQFP100 Package Marking

Figure 10.3. TQFP100 Package Marking

The package marking consists of:

- PPPPPPPPPP – The part number designation.
- TTTTTT – A trace or manufacturing code. The first letter is the device revision.
- YY – The last 2 digits of the assembly year.
- WW – The 2-digit workweek when the device was assembled.